

CLAIM AMENDMENT

The Applicants cancel claim 8 and currently amend claims 7, 9, 10.

1. – 6. (*withdrawn*)

7. (*previously & currently amended*) A metal embedded sensor comprising:

a. a metal structure comprising:

- i. a metal having a melting temperature above 660°C;
- ii. a coating metallic layer;
- iii. an embedding metallic layer on the coating metallic layer; and

b. a sensor embedded inside the metal structure;

~~wherein said metal structure is of a thickness and a metal such that externally induced local thermal rises occurring during molten metal forming processes above 660°C of a bulk material is transformed into balanced heat load onto the sensor for a uniformly expanding without cracking of it, said bulk material being molted in immediate contact to said metal structure, and~~
wherein said metal structure is in direct adhesive contact with said sensor.

8. (*cancelled*)

9. (*currently amended*) The metal embedded sensor of claim 7, wherein the embedding metallic layer is formed by laser deposition.

10. (*currently amended*) The metal embedded sensor of claim 7, wherein the coating metallic layer comprises a first metallic layer, and a second metallic layer on the first metallic layer.

11. (*original*) The metal embedded sensor of claim 10, wherein one or more of the first and the second metallic layers is formed by sputtering.

12. *(original)* The metal embedded sensor of claim 10, wherein one or more of the first and the second metallic layers is formed by electroplating.
13. *(original)* The metal embedded sensor of claim 10, wherein the first metallic layer is formed by sputtering, and the second metallic layer is formed by electroplating.
14. *(original)* The metal embedded sensor of claim 10, wherein the thickness of the first metallic layer is between about one and about three microns.
15. *(original)* The metal embedded sensor of claim 10, wherein the first metallic layer comprises a metal selected from the group consisting of copper, nickel, iron, and platinum.
16. *(original)* The metal embedded sensor of claim 10, wherein the thickness of the second metallic layer is between about one-quarter and about two millimeters.
17. *(original)* The metal embedded sensor of claim 10, wherein the second metallic layer comprises a metal selected from the group consisting of copper, nickel, iron, and platinum.
18. *(original)* The metal embedded sensor of claim 17, wherein the sensor is in the form of a fiber optic sensor.
19. *(original)* The metal embedded sensor of claim 18, further comprising an adhesive layer coating the sensor.

20. *(original)* The metal embedded sensor of claim 19, wherein the adhesive layer comprises titanium.
21. *(original)* The metal embedded sensor of claim 20, wherein the thickness of the adhesive layer is between about 2nm and about 3nm.
22. *(previously amended)* The metal embedded sensor of claim 7, wherein the sensor is in the form of a thin film thermo-mechanical sensor, and wherein the metal structure comprises:
- a. a coating metallic layer comprising
 - i. a first metallic layer;
 - ii. a second metallic layer on the first metallic layer, said second metallic layer selected from the group consisting of copper, nickel, iron, and platinum; and
 - b. an embedding metallic layer on the coating metallic layer.
23. *(previously amended)* The metal embedded sensor of claim 22, wherein the sensor comprises:
- a. a first insulating layer ;
 - b. a sensor layer disposed on the first insulating layer;
 - c. a second insulating layer disposed on the sensor layer; and
- wherein said first insulating layer and said second insulating layers are deposited of an insulating material with a maximum thickness for providing adequate electric insulation of said sensor layer in operation.
24. *(original)* The metal embedded sensor of claim 23, wherein the sensor further comprises an adhesive layer contacting the first insulating layer.
25. *(original)* The metal embedded sensor of claim 24, wherein the adhesive layer comprises titanium.

26. *(original)* The metal embedded sensor of claim 25, wherein the thickness of the adhesive layer is between about 2nm and about 3nm.
27. *(original)* The metal embedded sensor of claim 26, wherein the sensor further comprises a substrate contacting the adhesive layer.
28. *(original)* The metal embedded sensor of claim 27, wherein the substrate comprises a metallic substrate.
29. *(original)* The metal embedded sensor of claim 28, wherein the substrate comprises stainless steel.
30. *(original)* The metal embedded sensor of claim 23, wherein the sensor layer comprises constantan.
31. *(original)* The metal embedded sensor of claim 23, wherein the thickness of the first insulating layer is between about 10nm and about 15nm.
32. *(original)* The metal embedded sensor of claim 23, wherein the thickness of the second insulating layer is between about 10nm and about 15nm.
33. *(original)* The metal embedded sensor of claim 23, wherein the first and the second insulating layers comprise insulating oxides.
34. *(original)* The metal embedded sensor of claim 33, wherein the first and the second insulating layers comprise alumina.

35. – 63. (*withdrawn*)